2SA1729



# **High-Speed Switching Applications**

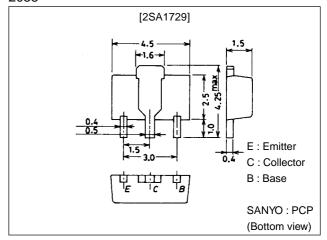
### **Features**

- · Adoption of FBET, MBIT processes.
- · Large current capacity.
- · Low collector-to-emitter saturation voltage.
- · Fast switching speed.
- · Small-sized package.

## **Package Dimensions**

unit:mm

2038



## **Specifications**

## Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>СВО</sub>		-50	V
Collector-to-Emitter Voltage	VCEO		-40	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		-5	V
Collector Current	IC		-1.5	Α
Collector Current (Pulse)	I <sub>CP</sub>		-3	Α
Collector Dissipation	PC	Mounted on ceramic board (250mm <sup>2</sup> ×0.8mm)	1.3	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Unit		
Collector Cutoff Current I <sub>CBO</sub> V Emitter Cutoff Current I <sub>EBO</sub> V		Conditions	min	typ	max	Offic
Collector Cutoff Current	ICBO	V <sub>CB</sub> =-40V, I <sub>E</sub> =0			-1	μΑ
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =-3V, I <sub>C</sub> =0			-1	μΑ
DC Current Gain	h <sub>FE</sub> 1	V <sub>CE</sub> =-2V, I <sub>C</sub> =-100mA	70*		280*	
	h <sub>FE</sub> 2	V <sub>CE</sub> =-2V, I <sub>C</sub> =-1.5A	25			
Gain-Bandwidth Product	fT	V <sub>CE</sub> =-2V, I <sub>C</sub> =-100mA		300		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =-10V, f=1MHz		18		pF
Collector-to-Emitter Saturatin Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =-800mA, I <sub>B</sub> =-40mA		-0.3	-0.8	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =-800mA, I <sub>B</sub> =-40mA		-0.9	-1.3	V

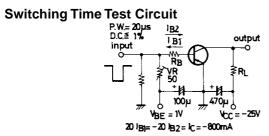
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Parameter	Symbol	Conditions		Ratings			
i arameter	Gyllibol	Conditions	min	typ	max	Unit	
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =-10μA, I <sub>E</sub> =0	<i>–</i> 50			V	
Collector-to-Emitter Saturation Voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> =-1mA, R <sub>BE</sub> =∞	-40			V	
Emitter-to-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =-10μA, I <sub>C</sub> =0	-5			V	
Turn-ON Time	ton	See specified Test Circuit		50	100	ns	
Storage Time	t <sub>stg</sub>	See specified Test Circuit		120	220	ns	
Turn-OFF Time	t <sub>off</sub>	See specified Test Circuit		150	300	ns	

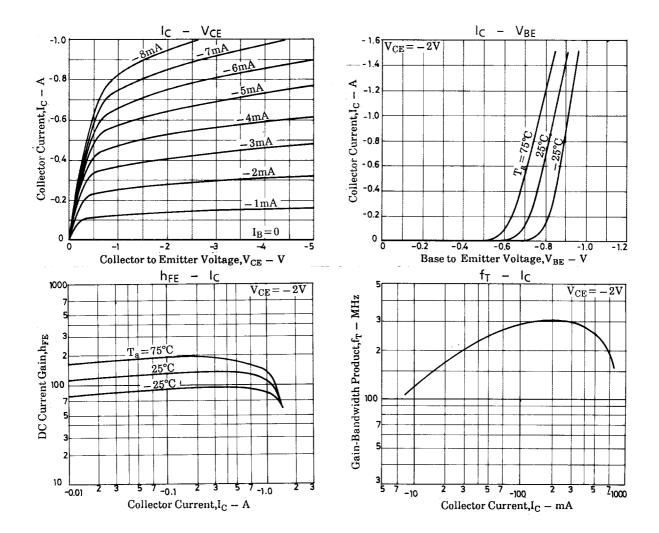
 $<sup>\</sup>ast$  : The 2SA1729 is classified by 100mA  $h_{FE}$  as follows :

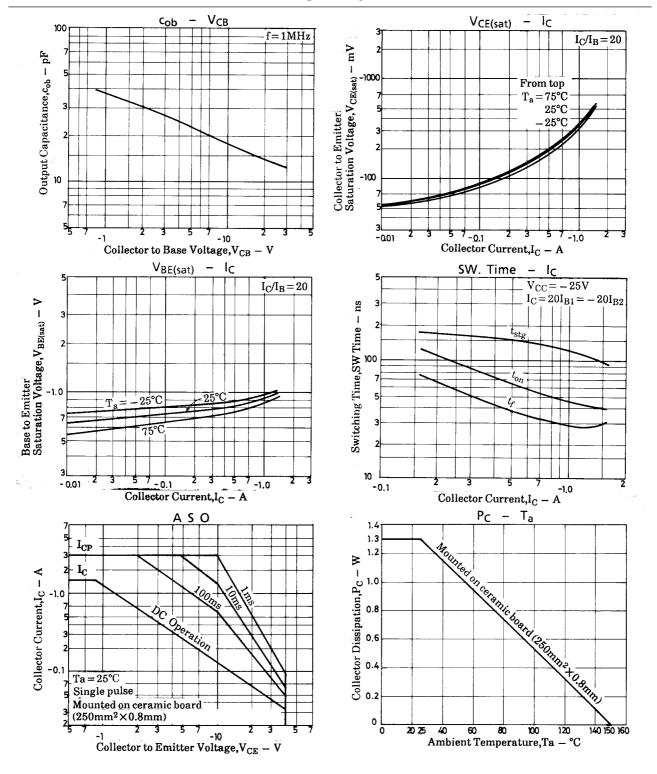
70	Q	140	100	R	200	140	S	280	
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Marking : AG h<sub>FE</sub> rank : Q, R, S



Unit (resistance :  $\Omega$ , capacitance : F)





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